nexperia

Quarterly Reliability Monitoring Results

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

Supplier		User Part Number						
Nexperia B.V. Name of Laboratory		BAS16L						
		Part Description						
		Nexperia DHAM	Small Signal E	Bipolar Diode				
Assembly reliability labs		MCD package						
Based on AEC-Q101 Test		Test Conditions	Duration	# Lots	# Quantity	# Rejects		
	TEST							
	Pre- and Post-Stress							
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below		
		JESD22-A113 Bake Tamb = 125 °C	24 hours					
	PC	Soak Tamb = $85 ^{\circ}$ C, RH = 85%	168 hours					
# A1	Preconditioning	Reflow soldering	3 cycles	113	9040	0		
		MIL-STD-750-1		-				
	HTRB	M1038 Method A						
		Tj = Tjmax, Vr = 100% of max. datasheet						
# B1	Bias	reverse voltage	1000 hours	67	5360	0		
	тс	JESD22-A104						
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	28	2240	0		
		JESD22-A102						
	AC	Tamb = 121 °C, RH = 100 %						
# A3 alt	Autoclave	Pressure = 205 kPa (29.7 psia)	96 hours	28	2240	0		
	H3TRB	JESD22-A101						
" • • • •	High Humidity High Temperature Reverse Bias	Tamb = 85 °C, RH = 85%, VR = 80 % of rated reverse voltage ^[1]	10001	20	22.42			
# A2 alt	remperature Reverse Blas		1000 hours	28	2240	0		
	101	MIL-STD-750 Method 1037						
# AF	IOL Intermittent Operating Life	ton = toff, devices powered to insure ΔT_j =	1000 have	20	2220	0		
# A5	Intermittent Operating Life		1000 hours	29	2320	0		
	RSH	JESD22-A111						
# C8	Resistance to Solder Heat		10 s	n	n a	n a		
# C0	SD	200 0 = 5 0	10.2	n.a.	n.a.	n.a.		
# C10	Solderability	J-STD-002		63	630	0		
# C10	,	d by test chamber set up and does not exceed		03	030	U		

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia DHAM	Small Signal Bipolar Diode	5260	0	0.70	1 265 1 00
DIAM		5360	0	0.79	1.26E+09

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